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Quarterly Reliability Monitoring Results

Supplier Nexperia B.V. Name of Laboratory Assembly reliability labs		User Part Number PESD2V5Y1BSF						
		NXP ICN8 Protection INDI						
		BD package						
		Test		Test Conditions	Duration	# Lots	# Quantity	# Rejects
	TEST Pre- and Post-Stress Electrical Test	T 1 25 00						
# 1	Electrical Test	Tamb = 25 °C	N/A	see below	all parts	see below		
	HTRB High Temperature Reverse	MIL-STD-750-1 M1038 Method A Tj = Tjmax, Vr = 100% of max. datasheet						
# 5	Bias	reverse voltage	1000 hours	43	3440	0		
# 7	TC Temperature Cycling	JESD22-A104 -40 °C to 125°C	1000 cycles	67	5360	0		
	AC	JESD22-A102 Tamb = 121 °C, RH = 100 %						
# 8	Autoclave	Pressure = 205 kPa (29.7 psia)	96 hours	n.a.	n.a.	n.a.		
	HAST Highly Accelerated Stress	JESD22-A110 Tamb = 130 °C, RH = 85%, VR = 80 % of						
# 9	Test	rated reverse voltage ^[1]	1000 hours	67	5360	0		
# 10	IOL Intermittent Operating Life	MIL-STD-750 Method 1037 ton = toff, devices powered to insure ΔTj = 100 °C for 15000 cycles	1000 hours					
# 10	Internittent Operating Life		1000 nours	n.a.	n.a.	n.a.		
	RSH	JESD22-A111						
# 20	Resistance to Solder Heat	260 °C ± 5 °C	10 s	n.a.	n.a.	n.a.		
	SD Solderability	J-STD-002						

[1] The maximum applied voltage is limited by test chamber set up and does not exceed 115V.

Calculation of FIT and MTTF

Test considered for FIT calculation: High Temperature Reverse Bias (HTRB, Test # 5)

Confidence level 60%, derated to 55 °C, activation energy 0.7 eV, test time 168 to 1000 hours

NXP ICN8 Protection INDI 3440 0 1.2 8.10E+08	Wafer Fab	Technology	Quantity	Rejects	Failure Rate (FIT)	MTTF (hrs)
	NXP ICN8	Protection INDI	3440	0	1.2	8.10E+08

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